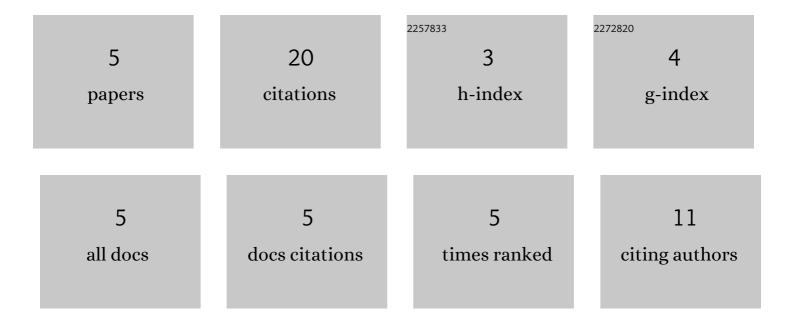
## Hiroyuki Kageshima

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/8682400/publications.pdf

Version: 2024-02-01



#	Article	IF	CITATIONS
1	Ab initio calculations for the effect of wet oxidation condition on the reaction mechanism at 4H–SiC/SiO <sub>2</sub> interface. Japanese Journal of Applied Physics, 2020, 59, SMMD01.	0.8	6
2	Surface-enhanced Raman scattering from buffer layer under graphene on SiC in a wide energy range from visible to near-infrared. Japanese Journal of Applied Physics, 2020, 59, 040902.	0.8	6
3	First-principles study of strain effect on oxygen vacancy in silicon oxide. Japanese Journal of Applied Physics, 2021, 60, 035504.	0.8	3
4	Theoretical study on role of edge termination for growth direction selectivity in chemical vapor deposition of hBN/graphene heterostructure on Cu surface. Applied Physics Express, 2021, 14, 085502.	1.1	3
5	First-principles study of pressure and SiO-incorporation effect on dynamical properties of silicon oxide. Japanese Journal of Applied Physics, 2019, 58, 111004.	0.8	2